1MBI30L-060(30A)

IGBT MODULE (L series)

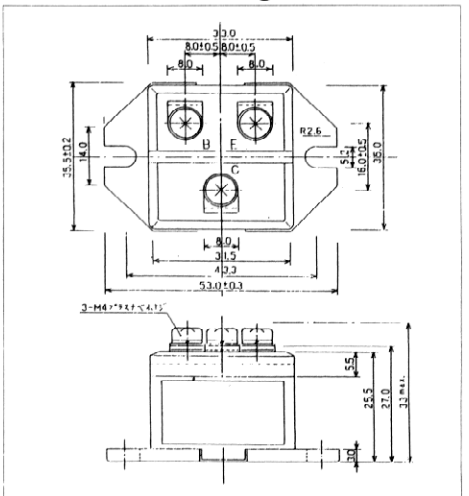
■ Features

- High Speed Switching
- Low Saturation Voltage
- Voltage Drive
- Isolated Package

■ Applications

- Ideal for Chopper Application
- AC and DC Servo Drive Supply
- Uninterruptible Power Supply
- Industrial Machines, such as Welding Machines

■ Outline Drawings



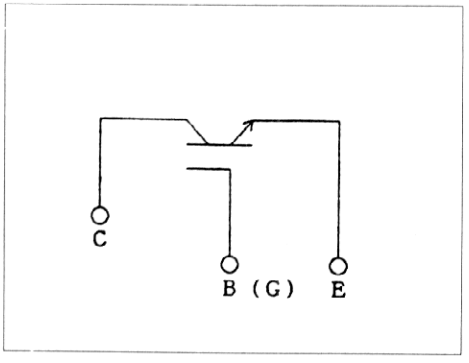
CASE	M110

■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings

Items		Symbols	Ratings	Units
Collecter-Emitter Voltage		V_{CES}	600	V
Gate-Emitter Voltage		V_{GES}	±20	V
Collecter Current	Continuous	I_C	30	A
	1ms	$I_{C\ pulse}$	60	
Max. Power Dissipation		P_C	120	W
Operating Temperature		T_j	+150	°C
Storage Temperature		T_{stg}	−40 to +125	°C
Isolation Voltage	AC. 1min.	V_{is}	2500	V
Screw Torque		Mounting *1	1.7	N•m
		Terminals *1	1.7	

■ Equivalent Circuit Schematic



*1 Recommendable Value 1.3 ~ 1.7 N•m (M4)

● Electrical Characteristics (Tj=25°C)

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collecter Current	I_{CES}	V_{GE}=0V V_{CE}=600V T_j=25°C			4.0	mA
Gate-Emitter Leackage Current	I_{GES}	V_{CE}=0V V_{GE}=±20V			100	nA
Gate-Emitter Threshold Voltage	$V_{GE\ (th)}$	V_{CE}=20V I_C=30mA	3.0	4.5	6.0	V
Collecter-Emitter Saturation Voltage	$V_{CE\ (sat)}$	V_{GE}=15V I_C=30A		2.7	3.5	V
Input Capacitance	C_{ies}	V_{GE}=0V		2850		pF
Output Capacitance	C_{oes}	V_{CE}=10V		–		
Reverse Transfer Capacitance	C_{res}	f=1MHz		–		
Turn-on Time *2	t_{on}	V_{CC}=300V		0.4	0.8	µs
	t_r	I_C=30A		0.3	0.6	
Turn-off Time *3	t_{off}	V_{GE}=±15V		0.6	1.0	
	t_f	R_G=82Ω		0.2	0.35	

*2 t_{on}, t_f: Resistive Load *3 t_{off}, t_f: Inductive Load

● Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	$R_{th\ (j-c)}$	IGBT			1.04	°C/W
	$R_{th\ (c-f)}$	With Thermal compound		0.06		